

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

N-Channel Silicon MOSFET

SCH1435 — General-Purpose Switching Device Applications

Features

- 1.8V drive
- · Halogen free compliance
- · Protection diode in

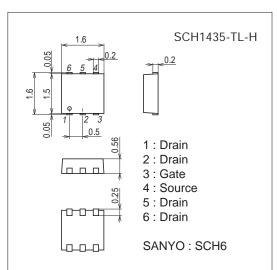
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		30	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	ID		3	Α
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	12	Α
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² x0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

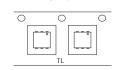
unit : mm (typ) 7028-002



Product & Package Information

Package : SCH6
 JEITA, JEDEC : SOT-563
 Minimum Packing Quantity : 5,000 pcs./reel

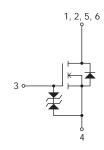
Packing Type: TL



Marking



Electrical Connection

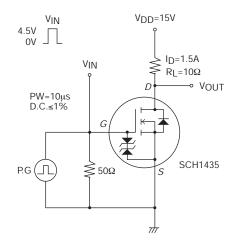


SCH1435

Electrical Characteristics at Ta=25°C

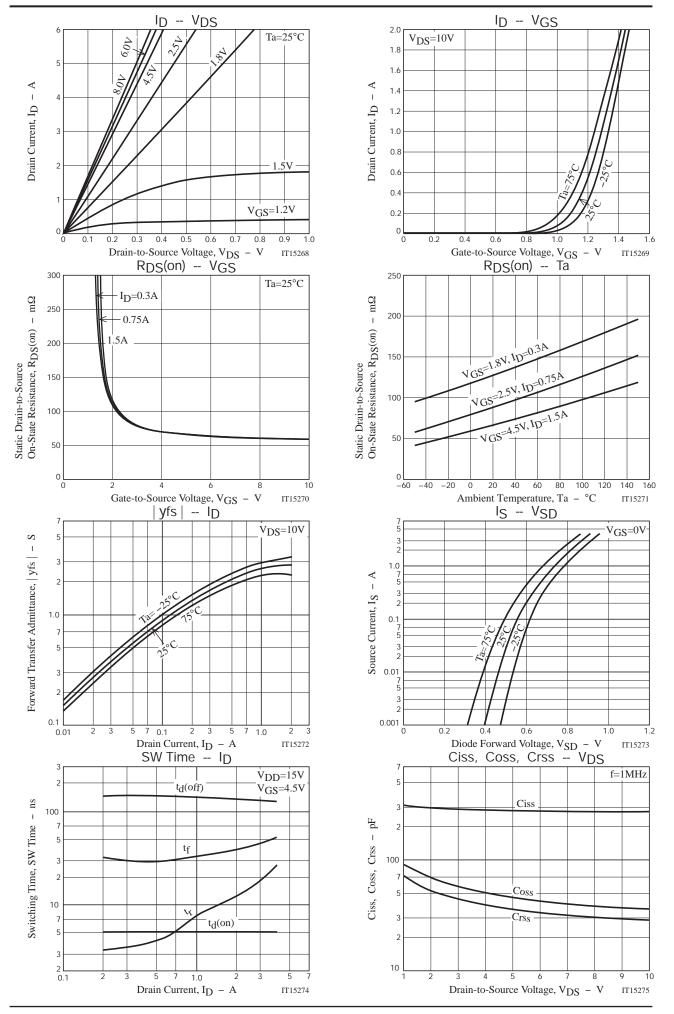
Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Syllibol	Conditions	min	typ	max	Unit	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V	
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ	
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ	
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V	
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1.5A		2.7		S	
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =1.5A, V _{GS} =4.5V		68	89	mΩ	
	R _{DS} (on)2	I _D =0.75A, V _{GS} =2.5V		90	126	mΩ	
	R _{DS} (on)3	I _D =0.3A, V _{GS} =1.8V		130	195	mΩ	
Input Capacitance	Ciss			265		pF	
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		35		pF	
Reverse Transfer Capacitance	Crss			28		pF	
Turn-ON Delay Time	t _d (on)			5.1		ns	
Rise Time	t _r	Considered Total Circuit		10		ns	
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		137		ns	
Fall Time	tf			36		ns	
Total Gate Charge	Qg			3.5		nC	
Gate-to-Source Charge	Qgs	V _{DS} =15V, V _{GS} =4.5V, I _D =3A		0.57		nC	
Gate-to-Drain "Miller" Charge	Qgd			0.93		nC	
Diode Forward Voltage	V _{SD}	I _S =3A, V _{GS} =0V		0.87	1.2	V	

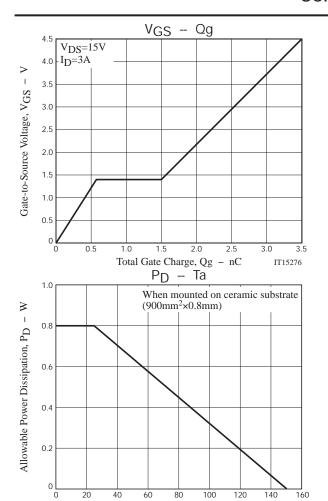
Switching Time Test Circuit



Ordering Information

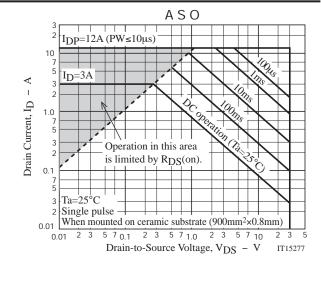
Device	Package	Shipping	memo	
SCH1435-TL-H	SCH1435-TL-H SCH6		Pb Free and Halogen Free	





Ambient Temperature, Ta - °C

IT15278

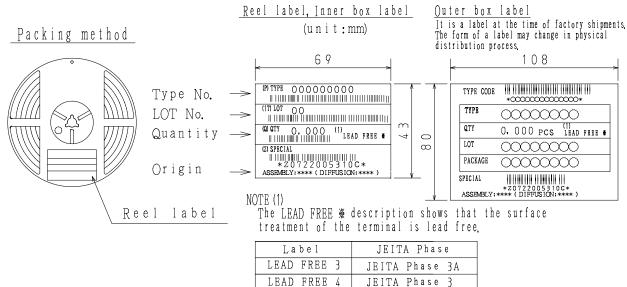


Taping Specification

SCH1435-TL-H

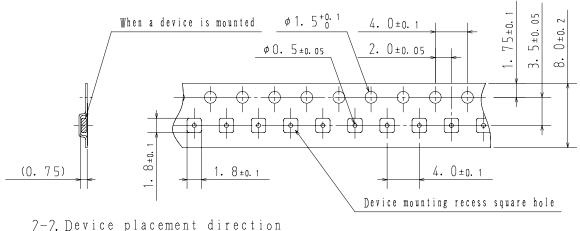
1. Packing Format

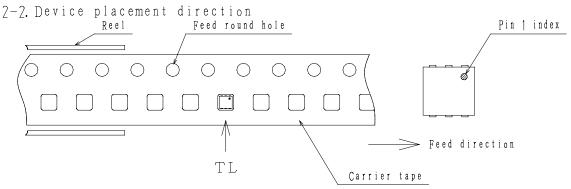
Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	g format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)		
SCH6	SCH6	5,000	25, 000	150,000	5 reels contained	6 inner boxes contained		
					Dimensions:mm (external)	Dimensions:mm (external)		
					$183 \times 72 \times 185$	440×195×210		



2. Taping configuration

2-1. Carrier tape size (unit:mm)

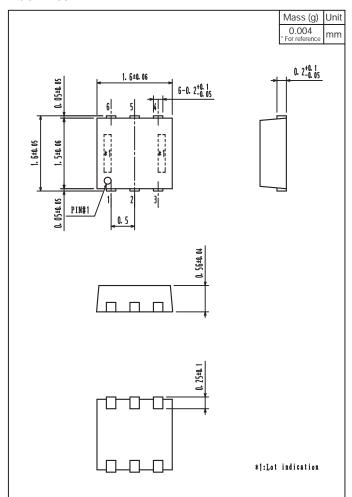




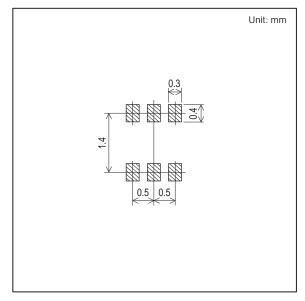
Those with pin 1 index on the feed hole side·····TL

Outline Drawing

SCH1435-TL-H



Land Pattern Example



Note on usage: Since the SCH1435 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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